



High Frequency Power Electronics

Prof. Daniel Costinett

ECE 581 Lecture 1
August 20, 2014



Course Info

- New course in design and modeling of “high frequency” power electronics
 - Course website: <http://web.eecs.utk.edu/courses/fall2014/ece581/>
- Goal of course is understanding of motivations and issues with high frequency power electronics; analysis and design techniques; applications
- Prerequisites: undergraduate Circuits sequence, Microelectronics, ECE 481 – Power Electronics, or equivalent



Contact Info

Instructor: Daniel Costinett

- Office: MK502
- OH: T 9-10; W 5-6; By appointment
- E-mail: Daniel.Costinett@utk.edu
- Email questions will be answered within 24 hours (excluding weekends)
- Please use **[ECE 581]** in the subject line



Course Structure

- Course meets MWF 9:00-9:50 am
- Plan to spend ~9 hours per week on course outside of lectures
- Grading:
 - Homework: 40%
 - One per week
 - Assignments due on Fridays unless otherwise noted on course website
 - Midterm: 25%
 - Tentatively scheduled for October 8th
 - Final: 35%



Assignments

- Assignments due *at the start of lecture* on the day indicated on the course schedule
- No late work will be accepted except in cases of documented medical emergencies
- Collaboration is encouraged on all assignments except quizzes and exams; Turn in your own work



Textbook and Materials

- The textbook
R.Erickson, D.Maksimovic, *Fundamentals of Power Electronics*, Springer 2001
will be used: chapters 19-20 and reference materials from prior chapters. The textbook is available on-line from campus network. Purchase is ~~not required~~ for this course.
- MATLAB/Simulink, LTSpice will be used; All installed in the Tesla Lab
- Lecture slides and notes, additional course materials, homework, due dates , etc. posted on the course website
- Additional information on course website



Introduction

- Why high frequency?
 - Power Density
 - Control Bandwidth
- Techniques
 - Devices
 - Control
 - Topologies
 - ~~Passives~~



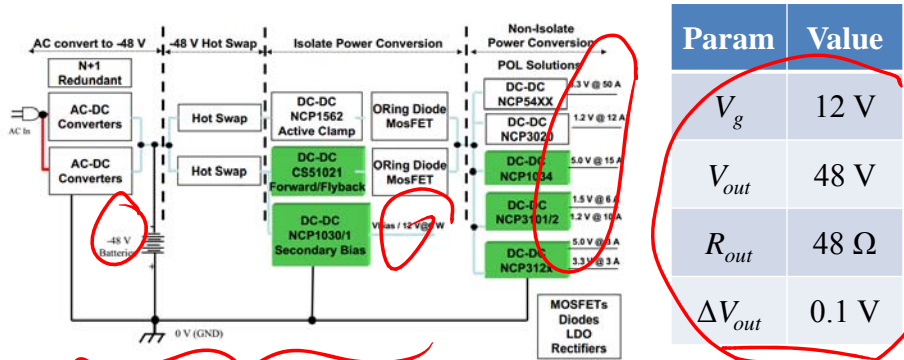
8 w Dimmable LED Driver



Voltage Regulation Module



Example Application - Telecom



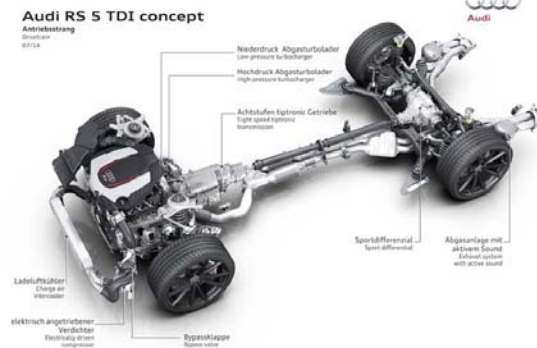
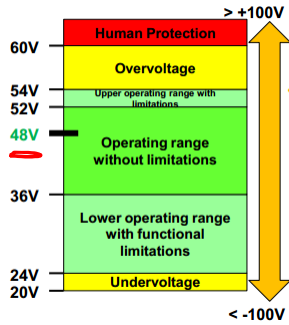
On Semi, "DC-DC Telecom & Networking Solutions", 2008



EV Networks

The (Hybrid) Electrical Vehicle ... driving new semiconductor technology

Maximize energy efficiency of the existing conventional electronic system

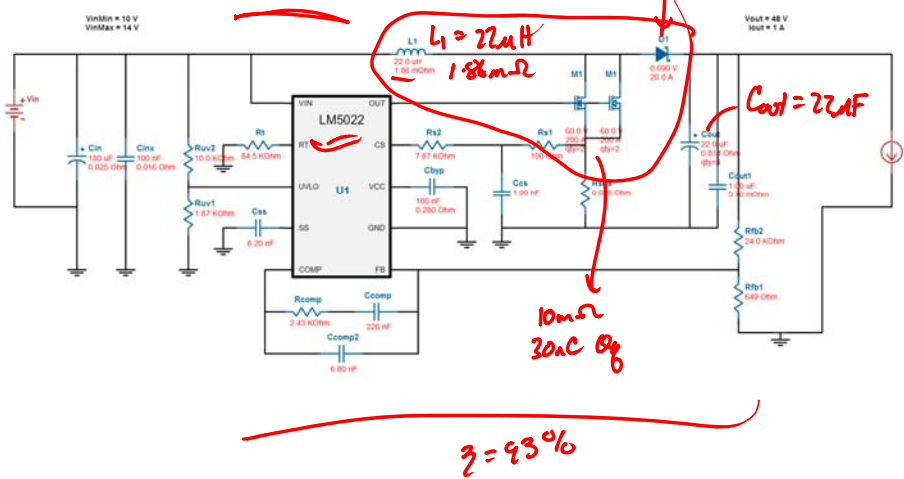


NXP Semi, "Semiconductors – enablers of future mobility concepts", 2011
 Audi, "Electric turbo and hybridization", 2014



Baseline Design

- Use TI WebBench (webench.ti.com) to get a baseline design



LTSpice Simulation

ECE 481 Analysis:

small-ripple
 $i_p(t) \approx I_L$ $v_{out}(t) \approx V$

$\langle v_c \rangle = V_g - D'V = \phi \rightarrow \frac{V}{V_g} = \frac{1}{D'}$

$\langle i_c \rangle = -\frac{V}{R} + D'I_c = \phi \rightarrow I_c = \frac{V}{R D'}$

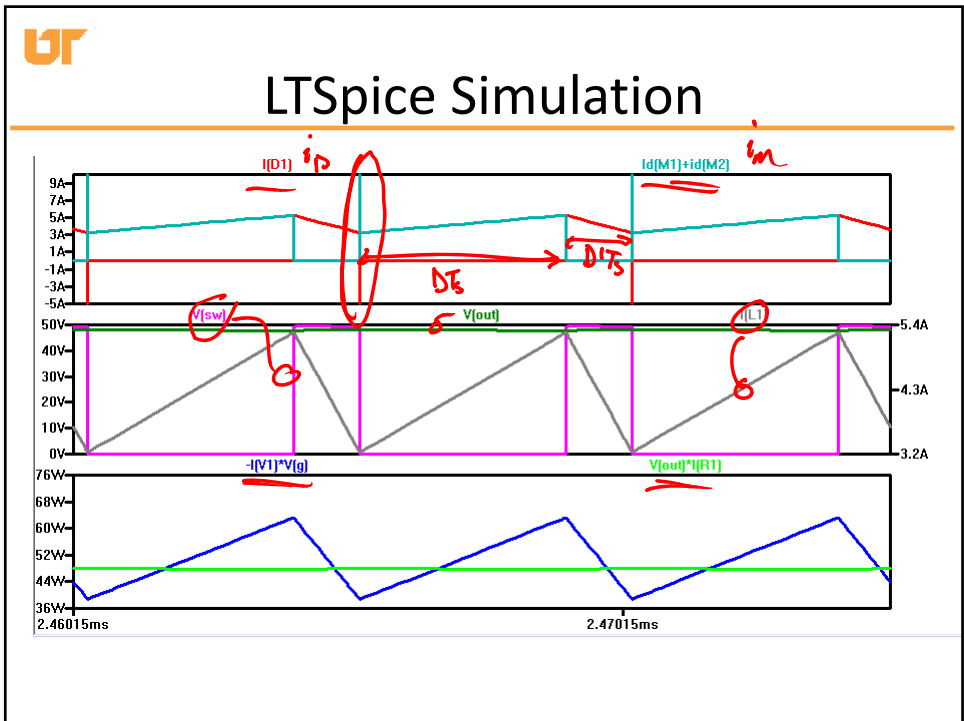
$D = 1 - \frac{V}{V_g} = 0.75$

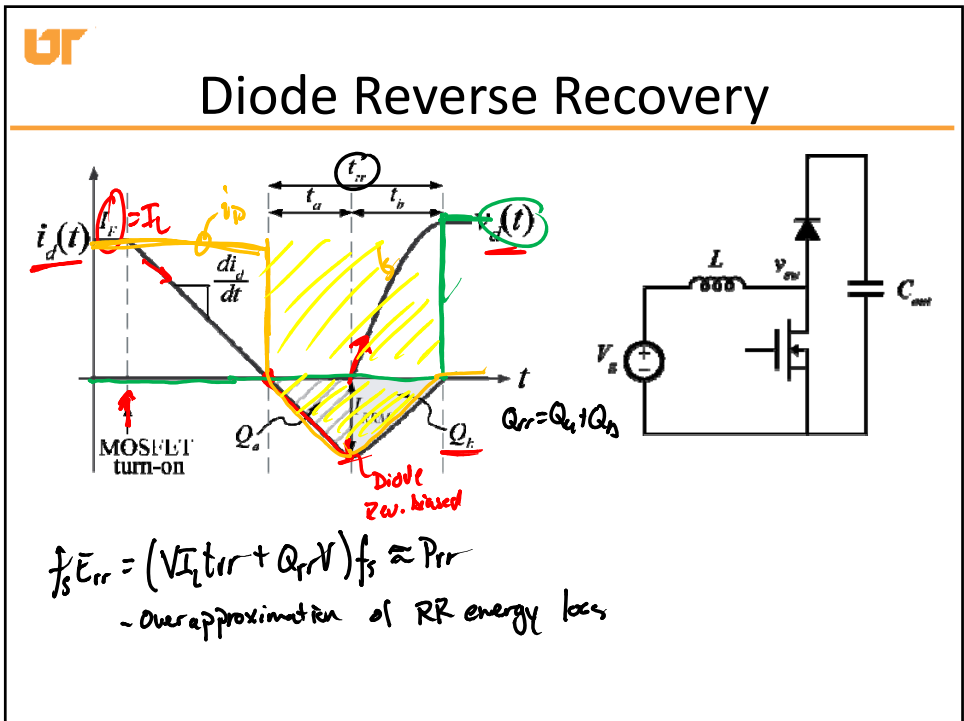
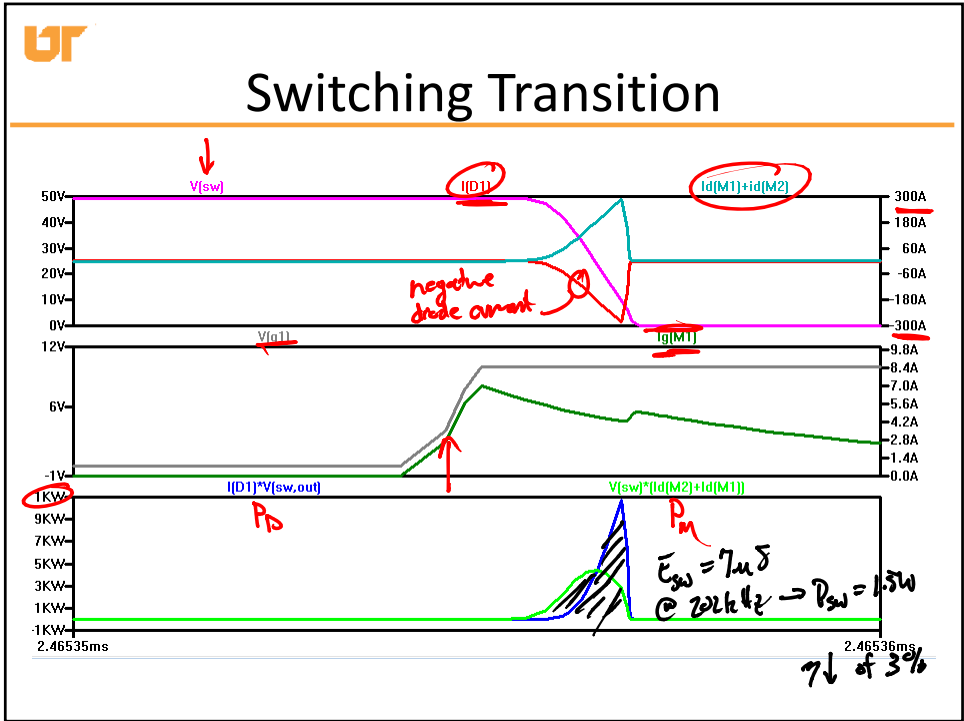
$\rightarrow I_c = 4A$

$\Delta v_{out} = \frac{1}{2} D T_s \frac{V}{RC} = 0.08V < 100mV$

$\Delta i_L = \frac{1}{2} \frac{V_g}{L} D T_s \approx 1A$

L	C _{out}	f _s	Diode	η (Sim)
22 μ H	22 μ F	202k	Si (FR)	93.9%







Datasheet RR Characteristics

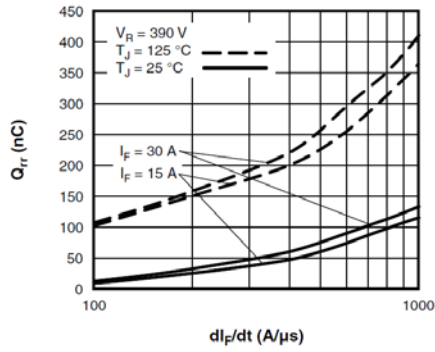


Fig. 10 - Typical Stored Charge vs. dI_F/dt

$$Q_{rr}, t_{rr} = f(I_F, \frac{dI_F}{dt}, T_j)$$

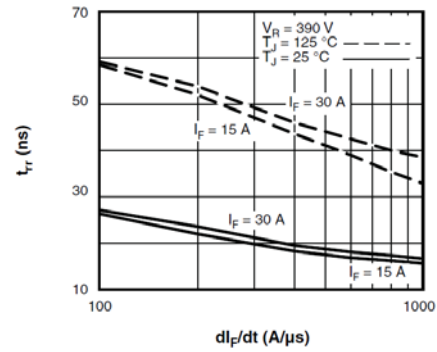


Fig. 9 - Typical Reverse Recovery Time vs. dI_F/dt